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Form PTO-1449 (modified)	Atty. Docket No.	Serial No.	
	11762.0266.NPUS00	08/530,661	
List of Patents and Publications for Applicant's	Applicants		
Information Disclosure Statement	Brent Keeth & Pierre C.	Fazan	
(Use several sheets if necessary)	Filing Date:	Group:	

## **U.S. Patent Documents**

Sept. 20, 1995

Exam. Init.	Ref. Des.	Document Number	Date	Name	Class	Sub Class	Filing Date of App.
File	Al	6,429,529	08/06/2002	Keeth	257	776	03/23/2000
/	A2	6.392,303	05/21/2002	Keeth	257	776	04/05/2001
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-	C1	Eimori et. al., "A Newly Designed Planar Stacked Capacitor Cell with High Dielectric Constant Film for 256Mbit DRAM," IEDM 1993 pp. 26.3.1-4.		

Examiner:	RELIEC	61/18	DATE CONSIDERED:	3 mu 03

EXAMINER: (SITIAL IF REFERENCE CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAWLENE THROUGH CITATION IE NOT IN CONFORMANCE AND NOT CONSIDERED. INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.